20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081 U.S.A.

TELEPHONE: (973) 376-2922

(212) 227-6005

FAX: (973) 376-8960

T4700 Series

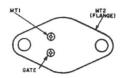
15-Ampere Silicon Triacs

For Phase-Control and Load-Switching Applications

- 800V, 125 Deg. C T_J Operating
- High dv/dt and di/dt Capability

- Low Switching Losses
 High Pulse Current Capability
 Low Forward and Reverse Leakage
- Sipos Oxide Glass Multilayer Passivation System
- Advanced Unisurface Construction
- Precise Ion Implanted Diffusion Source

TERMINAL DESIGNATIONS



JEDEC TO-213AA

MAXIMUM RATINGS, Absolute-Maximum Values:						
		T4700B	T4700D	T4700M	T4700N	
REPETITIVE PEAK OFF-STATE VOLTAGE:■						
Gate Open	V _{DROM}	200	400	600	800	V
RMS ON-STATE CURRENT:	DROM	200	100	000	000	٧
T _C = 95°C, conduction angle = 360°	I _{T(RMS)}			15		Δ
PEAK SURGE (NON-REPETITIVE) ON-STATE CURRENT:	ITSM	10				
For one full cycle of applied principal voltage	1011					
60 Hz (sinusoidal)		100				
For one full cycle of applied principal voltage						
(50-Hz, sinusoidal)		85				
For more than one full cycle of applied voltage		See Fig. 3				
PEAK GATE-TRIGGER CURRENT:						
For 1 µs max	I _{GTM}	44				
FUSING CURRENT (for triac protection):						
$T_J = -40 \text{ to } 100^{\circ}\text{ C}, t = 1.25 \text{ to } 10 \text{ ms} \dots$	²t	50				
GATE POWER DISSIPATION:						
Peak* (for 1 μ s max. and $I_{GTM} = \leq 4 A$)		16				
Average (averaging time = 10 ms max.)	PG(AV)	0.45				
	_ \					°C
Storage	- 9					
Operating (Case)	T _C		-401	to 125		°C
PIN TEMPERATURE (During soldering): At distances ≥ 1/32 in. (0.8 mm) from						
seating plane for 10 s max.	-		-			
seating plane for to stridt.	T _P		22	25		°C

For either polarity of main terminal 2 voltage (V_{MT2}) with reference to main terminal 1.

▲For temperature measurement reference point, see Dimensional Outline.

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

^{*}For either polarity of gate voltage (Vg) with reference to main terminal 1.

T4700 Series

ELECTRICAL CHARACTERISTICS

At Maximum Ratings and at Indicated Case Temperature (T_c) Unless Otherwise Specified

	SYMBOL		UNITS		
CHARACTERISTIC		For All Types Unless Otherwise Specified			
		Min.	Тур.	Max.	
Peak Off-State Current Gate open, T _J = 125°C, V _{DROM} = Max. rated value	t _{DROM}	_	0.2	4	mA
Instantaneous On-State Voltage ⁶ For i _⊤ = 30A (peak), T _C 25° C	V _T	_	1.6	2.0	V
DC Holding Current Gate open, Initial principal current = 150 mA (DC), v _D = 12V: T _C = 25°C For other case temperatures	I _{HO}	-	15 See Fig. 5	60	mA
Critical Rate of Applied Commutating Voltage ⁶ For v _D = V _{DROM} , I _{T(RIMS)} = 15 A, commutating di/dt = 8 A/ms, and gate unenergized At T _C = +95° C	dv/dt	2	10	_	V/μs
Critical Rate of Rise of Off-State Voltage For V _D = V _{DROM} , exponential voltage rise, and gate open At T _C = 125° C T4700B T4700D T4700M T4700N	dv/dt	30 20 15 10	150 100 75 50		V/μs
DC Gate-Trigger Current \bullet \blacksquare For $v_D = 6$ volts (dc), $R_L = 12$ ohms, $T_C = +25^\circ$, and Specified Triggering Mode: I† Mode: V_{72} is positive, V_G is positive. I Mode: V_{72} is positive, V_G is negative. II† Mode: V_{72} is negative, V_G is positive. III Mode: V_{72} is negative, V_G is negative. For other case temperatures.	I _{GT}	_ _ _ _ _ s	15 35 35 15 ee Figs. 7 8	30 80 80 30	mA
DC Gate-Trigger Voltage For v _D = 6 volts (dc) and R _L = 12 ohms At T _C = +25° For other case temperatures For v _D = V _{DROM} , R _L = 125 Ω, T _C = 125° C	V _{GT}	0.2	1 See Fig. 1	2.5	V
Gate-Controlled Turn-On Time (Delay Time + Rise Time) For $v_D = V_{DROM}$, $I_G = 160$ mA, $t_r = 0.1 \mu$ s, $I_T = 25$ A (peak), $T_C = 25^{\circ}$ C	t _{gl}	_	1.6	2.5	μs
Thermal Resistance: Junction-to-Case	R _{NC}		_	1.3	°C/W

⁸For either polarity of main terminal 2 voltage (V_{T2}) with reference to main terminal 1. [®]For either polarity of gate voltage (V_G) with reference to main terminal 1.